



# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## General Description

The MAX4651/MAX4652/MAX4653 quad analog switches feature 4Ω max on-resistance ( $R_{ON}$ ) when operating from a single +5V supply.  $R_{ON}$  is matched between switches to 0.2Ω max and is flat (0.8Ω max) over the specified signal range. Each switch can handle Rail-to-Rail® analog signals. Off-leakage current is 0.1nA at +25°C. These switches are ideal in low-distortion applications and are the preferred solution over mechanical relays in automated test equipment or applications where current switching is required. They have low power requirements, require less board space, and are more reliable than mechanical relays.

The MAX4651/MAX4652/MAX4653 operate from a single +1.8V to +5.5V supply, making them ideal for use in battery-powered applications.

The MAX4651 has four normally closed (NC) switches, the MAX4652 has four normally open (NO) switches, and the MAX4653 has two NO and two NC switches. These devices are available in 16-pin TSSOP and SO packages.

## Applications

- Battery-Powered Systems
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Sample-and-Hold Circuits
- Communications Circuits
- Relay Replacement

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

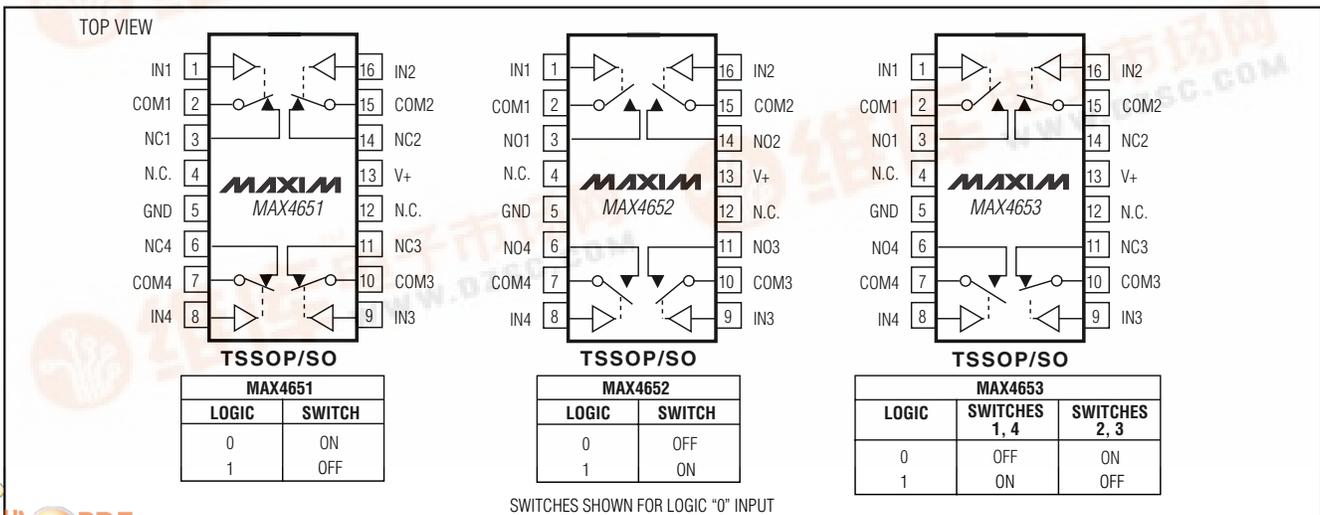
## Features

- ◆ On-Resistance
  - 4Ω max at 5V
  - 7Ω max at 3V
- ◆ On-Resistance Flatness
  - 0.8Ω max at 5V
  - 2.5Ω max at 3V
- ◆ On-Resistance Matching
  - 0.2Ω max (+2.7V to +5.5V)
- ◆ +1.8V to +5.5V Single-Supply Voltage
- ◆ +1.8V Operation
  - On-Resistance 30Ω typ Over Temperature
  - $t_{ON}$  20ns typ,  $t_{OFF}$  12ns typ
- ◆ TTL/CMOS-Logic Compatible
- ◆ Crosstalk
  - 100dB at 1MHz
- ◆ Off-Isolation
  - 75dB at 1MHz
- ◆ Rail-to-Rail Signal Range

## Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4651EUE	-40°C to +85°C	16 TSSOP
MAX4651ESE	-40°C to +85°C	16 SO
MAX4652EUE	-40°C to +85°C	16 TSSOP
MAX4652ESE	-40°C to +85°C	16 SO
MAX4653EUE	-40°C to +85°C	16 TSSOP
MAX4653ESE	-40°C to +85°C	16 SO

## Pin Configurations/Functional Diagrams/Truth Tables



MAX4651/MAX4652/MAX4653

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## ABSOLUTE MAXIMUM RATINGS

V+ to GND .....-0.3 to +6V  
 IN\_, COM\_, NO\_, NC\_ to GND (Note 1).....-0.3V to (V+ + 0.3V)  
 Continuous Current (NO\_, NC\_, COM\_).....±50mA  
 Peak Current (NO\_, NC\_, COM\_, pulsed at 1ms  
 10% duty cycle).....±100mA

Continuous Power Dissipation (T<sub>A</sub> = +70°C)  
 16-Pin TSSOP (derate 5.7mW/°C above +70°C) .....457mW  
 16-Pin SO (derate 8mW/°C above +70°C).....640mW  
 Operating Temperature Range .....-40°C to +85°C  
 Storage Temperature Range .....-65°C to +150°C  
 Lead Temperature (soldering, 10s) .....+300°C

**Note 1:** Signals on NO\_, NC\_, COM\_, or IN\_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = 4.5V to 5.5V, V<sub>IH</sub> = 2.4V, V<sub>IL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V+ = 5V, T<sub>A</sub> = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>ANALOG SWITCH</b>							
Input Voltage Range	V <sub>COM_</sub> , V <sub>NO_</sub> , V <sub>NC_</sub>		0		V+	V	
COM_ to NO_ or NC_ On-Resistance	R <sub>ON</sub>	I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>NC_</sub> = 0 to V+, V+ = 4.5V	T <sub>A</sub> = +25°C	2.5	4	Ω	
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		4.5		
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Note 3)	ΔR <sub>ON</sub>	I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>NC_</sub> = 0 to V+, V+ = 4.5V	T <sub>A</sub> = +25°C	0.05	0.2	Ω	
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		0.3		
On-Resistance Flatness (Note 4)	R <sub>FLAT(ON)</sub>	I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>NC_</sub> = 0 to V+, V+ = 4.5V	T <sub>A</sub> = +25°C	0.5	0.8	Ω	
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		1		
Off-Leakage Current (NO_ or NC_) (Note 5)	I <sub>NO_</sub> , I <sub>NC_</sub>	V <sub>COM</sub> = 1V, 4.5V; V <sub>NO_</sub> or V <sub>NC_</sub> = 4.5V, 1V; V+ = 5.5V	T <sub>A</sub> = +25°C	-0.1	0.01	0.1	nA
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		-0.2	0.2	
COM_ Off-Leakage Current (Note 5)	I <sub>COM(OFF)</sub>	V <sub>COM</sub> = 1V, 4.5V; V <sub>NO_</sub> or V <sub>NC_</sub> = 4.5V, 1V; V+ = 5.5V	T <sub>A</sub> = +25°C	-0.1	0.01	0.1	nA
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		-0.2	0.2	
COM_ On-Leakage Current (Note 5)	I <sub>COM(ON)</sub>	V+ = 5.5V, V <sub>COM</sub> = 1V, 4.5V; V <sub>NO_</sub> or V <sub>NC_</sub> = 1V, 4.5V or floating	T <sub>A</sub> = +25°C	-0.1	0.01	0.1	nA
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		-0.2	0.2	
<b>LOGIC INPUT (IN_)</b>							
Input High	V <sub>IH</sub>		2.4			V	
Input Low	V <sub>IL</sub>				0.8	V	
Logic Input Current	I <sub>IN</sub>		-100	5	100	nA	

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MAX4651/MAX4652/MAX4653

## ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = 4.5V to 5.5V, V<sub>IH</sub> = 2.4V, V<sub>IL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V+ = 5V, T<sub>A</sub> = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>SWITCH DYNAMIC CHARACTERISTICS</b>						
Turn-On Time (Note 5)	t <sub>ON</sub>	V <sub>NO_</sub> = V <sub>VNC_</sub> = 3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, Figure 2	T <sub>A</sub> = +25°C	11	14	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		16	
Turn-Off Time (Note 5)	t <sub>OFF</sub>	V <sub>NO_</sub> = V <sub>VNC_</sub> = 3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, Figure 2	T <sub>A</sub> = +25°C	6	8	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		10	
Break-Before-Make (MAX4653 only) (Note 5)		V <sub>NO_</sub> = V <sub>VNC_</sub> = 3V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF	T <sub>A</sub> = +25°C	1	6	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>	1		
Charge Injection	Q	V <sub>GEN</sub> = 2V, C <sub>L</sub> = 1.0nF, R <sub>GEN</sub> = 0, Figure 3		2		pC
NO_ or NC_ Off-Capacitance	C <sub>OFF</sub>	V <sub>NO_</sub> = V <sub>VNC_</sub> = GND, f = 1MHz, Figure 6		16		pF
COM_ Off-Capacitance	C <sub>COM(OFF)</sub>	V <sub>COM_</sub> = GND, f = 1MHz, Figure 6		16		pF
COM_ On-Capacitance	C <sub>COM(ON)</sub>	V <sub>COM_</sub> = V <sub>NO_</sub> , V <sub>VNC_</sub> = GND, f = 1MHz, Figure 7		32		pF
Off-Isolation (Note 6)	V <sub>ISO</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, Figure 4		-50		dB
		R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 1MHz, Figure 4		-75		
Crosstalk (Note 7)	V <sub>CT</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, Figure 5		-80		dB
		R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 1MHz, Figure 5		-100		
Total Harmonic Distortion	THD	R <sub>L</sub> = 600Ω, f = 20Hz to 20kHz		0.02		%
<b>POWER SUPPLY</b>						
Positive Supply Current	I+	V+ = 5.5V, V <sub>IN</sub> = 0 or V+		0.001	1.0	μA

## ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = 2.7V to 3.3V, V<sub>IH</sub> = 2.0V, V<sub>IL</sub> = 0.4V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V+ = 3V, T<sub>A</sub> = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>ANALOG SWITCH</b>						
Input Voltage Range	V <sub>COM_</sub> , V <sub>NO_</sub> , V <sub>VNC_</sub>		0		V+	V
COM_ to NO_ or NC_ On-Resistance	R <sub>ON</sub>	V+ = 2.7V, I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>VNC_</sub> = 0 to V+	T <sub>A</sub> = +25°C	5	7	Ω
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		8	
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Note 3)	ΔR <sub>ON</sub>	V+ = 2.7V, I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>VNC_</sub> = 0 to V+	T <sub>A</sub> = +25°C	0.1	0.2	Ω
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		0.3	
On-Resistance Flatness (Note 4)	R <sub>FLAT(ON)</sub>	V+ = 2.7V, I <sub>COM</sub> = 10mA, V <sub>NO_</sub> or V <sub>VNC_</sub> = 0 to V+	T <sub>A</sub> = +25°C	1.2	2.5	Ω
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		3	

# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V<sub>+</sub> = 2.7V to 3.3V, V<sub>IH</sub> = 2.0V, V<sub>IL</sub> = 0.4V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V<sub>+</sub> = 3V, T<sub>A</sub> = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>LOGIC INPUT (IN<sub>-</sub>)</b>						
Input High	V <sub>IH</sub>		2.0			V
Input Low	V <sub>IL</sub>				0.4	V
Logic Input Current	I <sub>IN</sub>		-100	5	100	nA
<b>SWITCH DYNAMIC CHARACTERISTICS</b>						
Turn-On Time (Note 5)	t <sub>ON</sub>	V <sub>NO<sub>-</sub></sub> = V <sub>VNC<sub>-</sub></sub> = 2V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, Figure 2	T <sub>A</sub> = +25°C	13	16	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		20	
Turn-Off Time (Note 5)	t <sub>OFF</sub>	V <sub>NO<sub>-</sub></sub> = V <sub>VNC<sub>-</sub></sub> = 2V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF, Figure 2	T <sub>A</sub> = +25°C	7	10	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		12	
Break-Before-Make (MAX4653 only) (Note 5)		V <sub>NO<sub>-</sub></sub> = V <sub>VNC<sub>-</sub></sub> = 2V, R <sub>L</sub> = 300Ω, C <sub>L</sub> = 35pF	T <sub>A</sub> = +25°C	1	7	ns
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>	1		
Charge Injection	Q	V <sub>GEN</sub> = 1.5V, C <sub>L</sub> = 1.0nF, R <sub>GEN</sub> = 0, Figure 3		2		pC
NO <sub>-</sub> or NC <sub>-</sub> Off-Capacitance	C <sub>OFF</sub>	V <sub>NO<sub>-</sub></sub> = V <sub>VNC<sub>-</sub></sub> = GND, f = 1MHz, Figure 6		16		pF
COM <sub>-</sub> Off-Capacitance	C <sub>COM(OFF)</sub>	V <sub>COM<sub>-</sub></sub> = GND, f = 1MHz, Figure 6		16		pF
COM <sub>-</sub> On-Capacitance	C <sub>COM(ON)</sub>	V <sub>COM<sub>-</sub></sub> = V <sub>NO<sub>-</sub></sub> , V <sub>VNC<sub>-</sub></sub> = GND, f = 1MHz, Figure 7		32		pF
Off-Isolation (Note 6)	V <sub>ISO</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, Figure 4		-50		dB
			R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 1MHz, Figure 4		-75	
Crosstalk (Note 7)	V <sub>CT</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, Figure 5		-80		dB
		R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 1MHz, Figure 5		-100		
Total Harmonic Distortion	THD	R <sub>L</sub> = 600Ω, f = 20Hz to 20kHz		0.02		%
<b>POWER SUPPLY</b>						
Positive Supply Current	I <sub>+</sub>	V <sub>+</sub> = 3.3V, V <sub>IN</sub> = 0 or V <sub>+</sub>		0.001	1.0	μA

**Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

**Note 3:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 4:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

**Note 5:** Guaranteed by design.

**Note 6:** Off-Isolation =  $20\log_{10}(V_{COM} / V_{NO})$ , where V<sub>COM</sub> = output and V<sub>NO</sub> = input to off switch.

**Note 7:** Between any two switches.

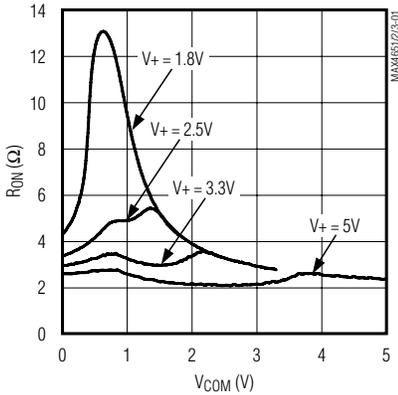
# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Typical Operating Characteristics

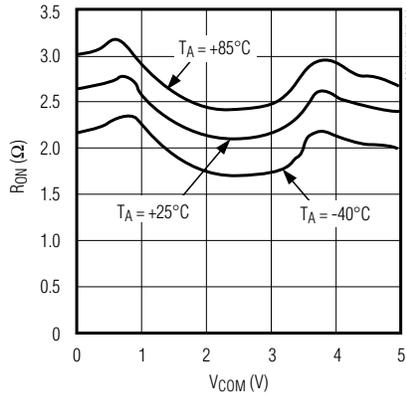
( $V_+ = 5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

MAX4651/MAX4652/MAX4653

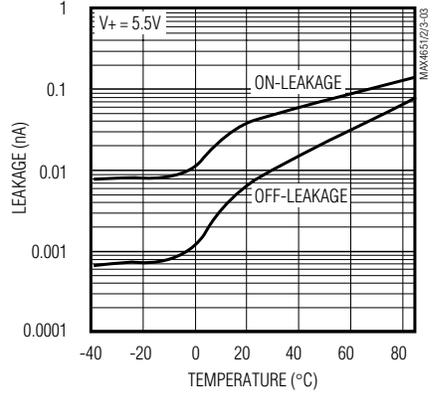
**ON-RESISTANCE vs.  $V_{COM}$  AND SUPPLY VOLTAGE**



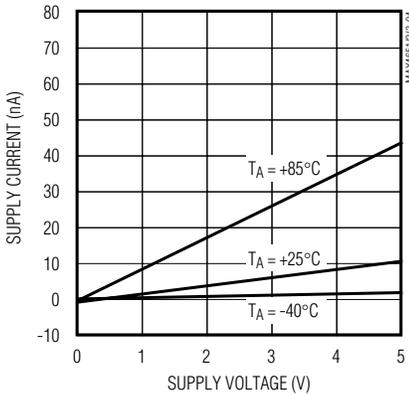
**ON-RESISTANCE vs.  $V_{COM}$  AND TEMPERATURE**



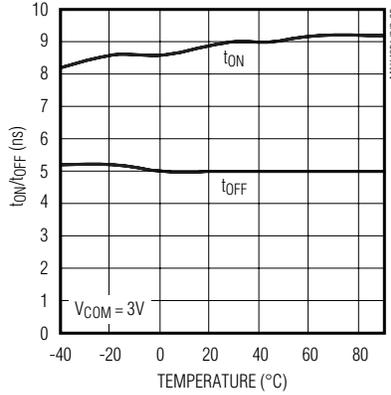
**ON/OFF-LEAKAGE CURRENT vs. TEMPERATURE**



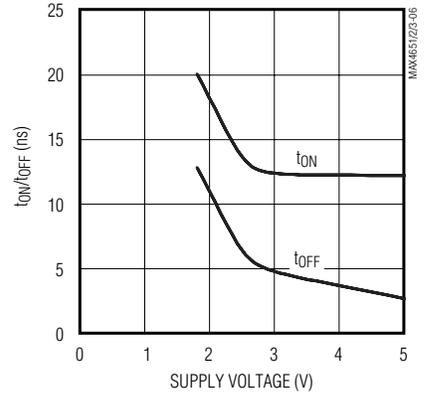
**SUPPLY CURRENT vs. SUPPLY VOLTAGE AND TEMPERATURE**



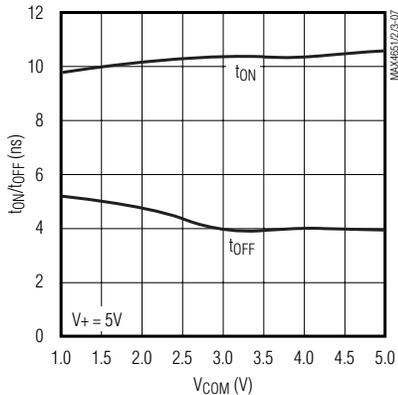
**TURN-ON/TURN-OFF TIMES vs. TEMPERATURE**



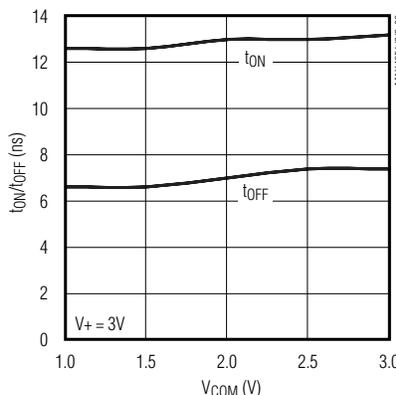
**TURN-ON/TURN-OFF TIMES vs. SUPPLY VOLTAGE**



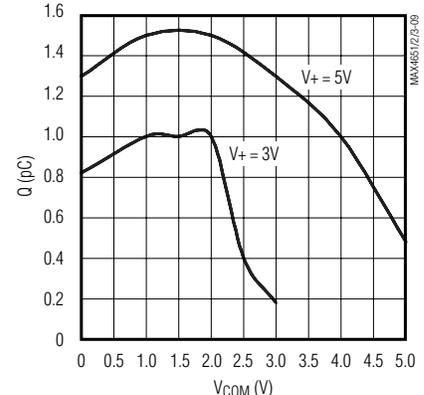
**TURN-ON/TURN-OFF TIMES vs.  $V_{COM}$**



**TURN-ON/TURN-OFF TIMES vs.  $V_{COM}$**



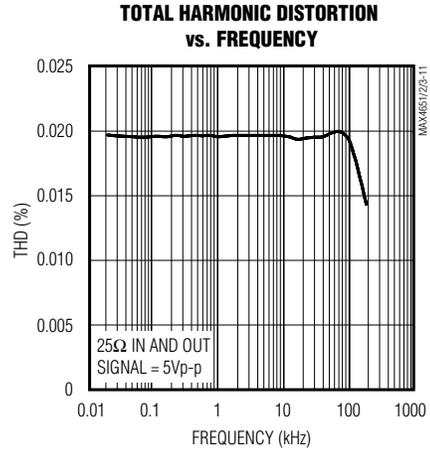
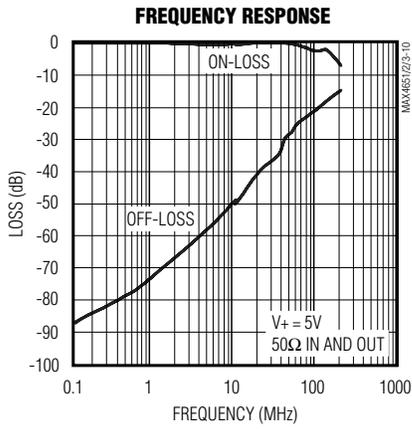
**CHARGE INJECTION vs.  $V_{COM}$**



# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Typical Operating Characteristics (continued)

(V+ = 5V, TA = +25°C, unless otherwise noted.)



# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Pin Description

PIN			NAME	FUNCTION
MAX4651	MAX4652	MAX4653		
1	1	1	IN1	Digital Control Input 1
2	2	2	COM1	Analog Switch 1, Common
3	–	–	NC1	Analog Switch 1, Normally Closed
–	3	3	NO1	Analog Switch 1, Normally Open
4, 12	4, 12	4, 12	N.C.	No Connection. Not internally connected.
5	5	5	GND	Ground, Negative Supply Input
6	–	–	NC4	Analog Switch 4, Normally Closed
–	6	6	NO4	Analog Switch 4, Normally Open
7	7	7	COM4	Analog Switch 4, Common
8	8	8	IN4	Digital Control Input 4
9	9	9	IN3	Digital Control Input 3
10	10	10	COM3	Analog Switch 3, Common
11	–	11	NC3	Analog Switch 3, Normally Closed
–	11	–	NO3	Analog Switch 3, Normally Open
13	13	13	V+	Positive Supply Voltage Input
14	–	14	NC2	Analog Switch 2, Normally Closed
–	14	–	NO2	Analog Switch 2, Normally Open
15	15	15	COM2	Analog Switch 2, Common
16	16	16	IN2	Digital Control Input 2

MAX4651/MAX4652/MAX4653

## Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

### Detailed Description

The MAX4651/MAX4652/MAX4653 are low on-resistance, low-voltage analog switches that operate from a single +1.8V to +5.5V supply. CMOS switch construction allows processing analog signals that are within the supply voltage range (GND to V+).

### Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by the logic inputs, NO or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1). Adding these diodes reduces the analog signal by one diode drop below V+ and one diode drop above GND, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and GND should not exceed 6V.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A 0.1μF capacitor connected from V+ to GND is adequate for most applications.

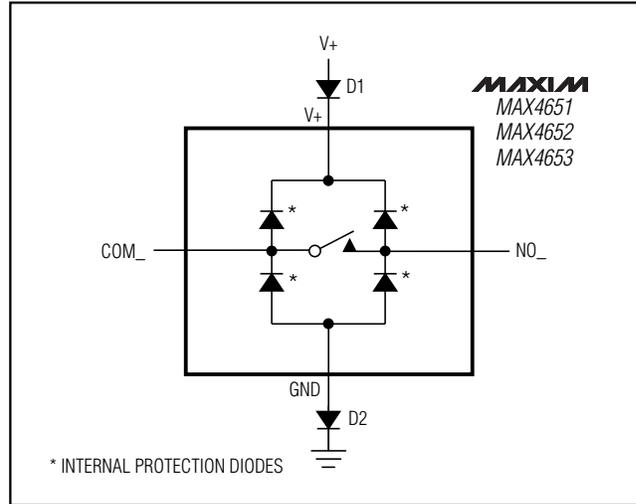


Figure 1. Overvoltage Protection Using External Blocking Diodes

### Chip Information

TRANSISTOR COUNT: 205

# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Timing Diagrams/Test Circuits

MAX4651/MAX4652/MAX4653

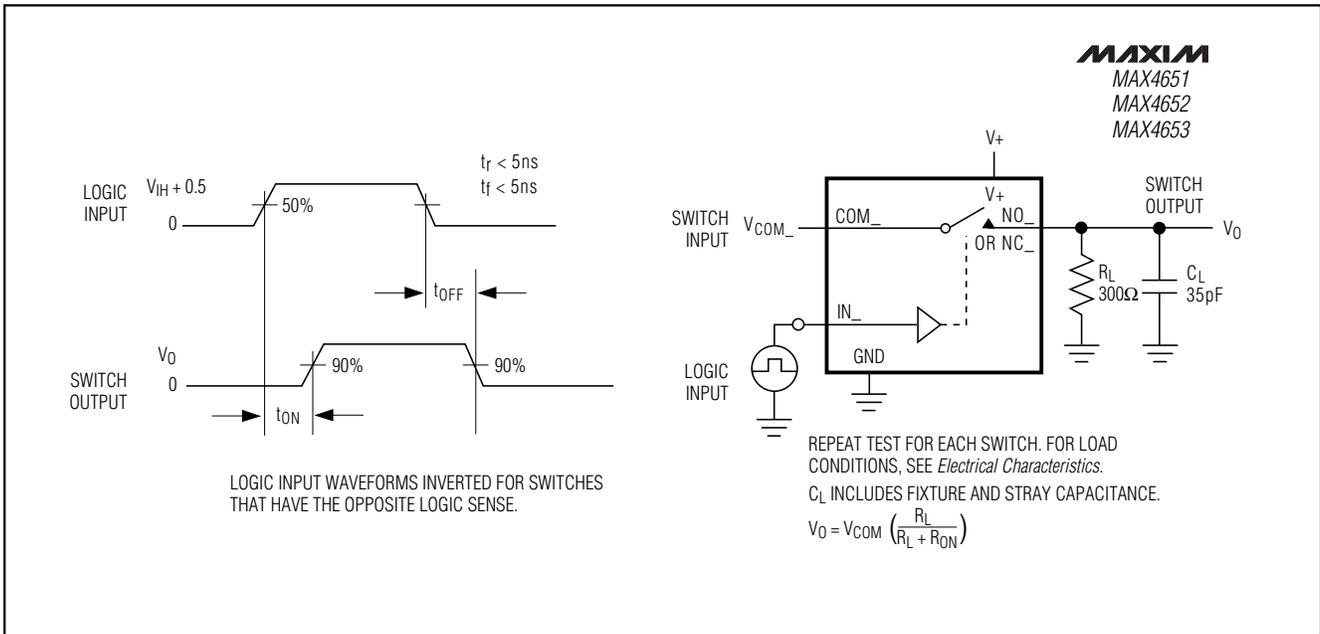


Figure 2. Switching-Time Test Circuit

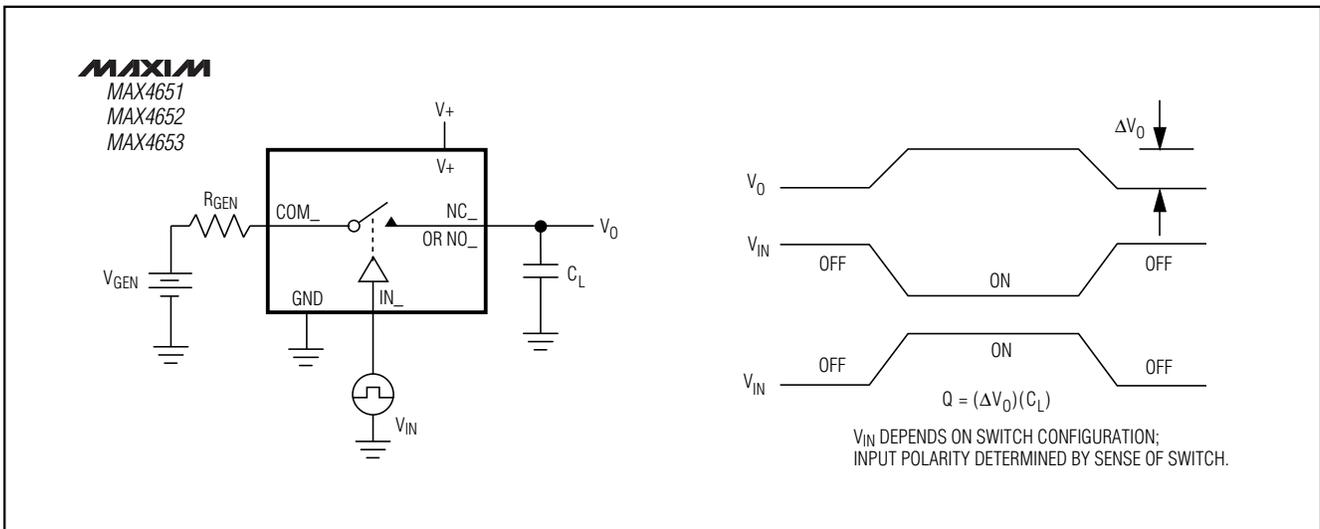


Figure 3. Charge-Injection Test Circuit

# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Timing Diagrams/Test Circuits (continued)

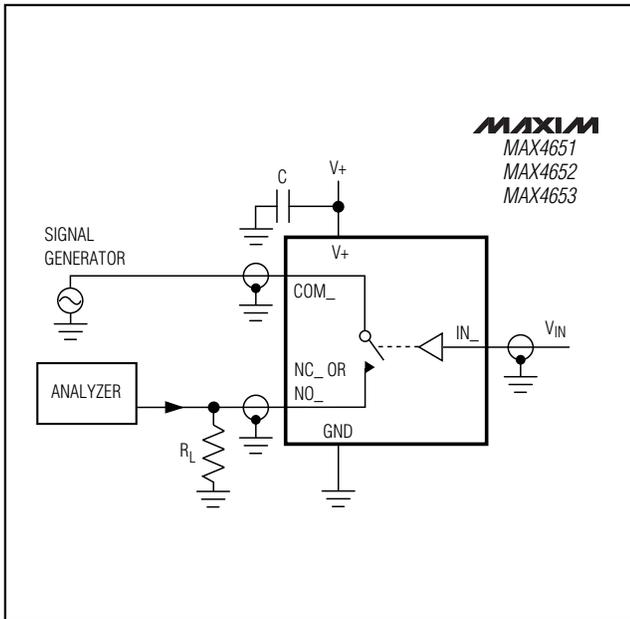


Figure 4. Off-Isolation Test Circuit/On-Channel Bandwidth

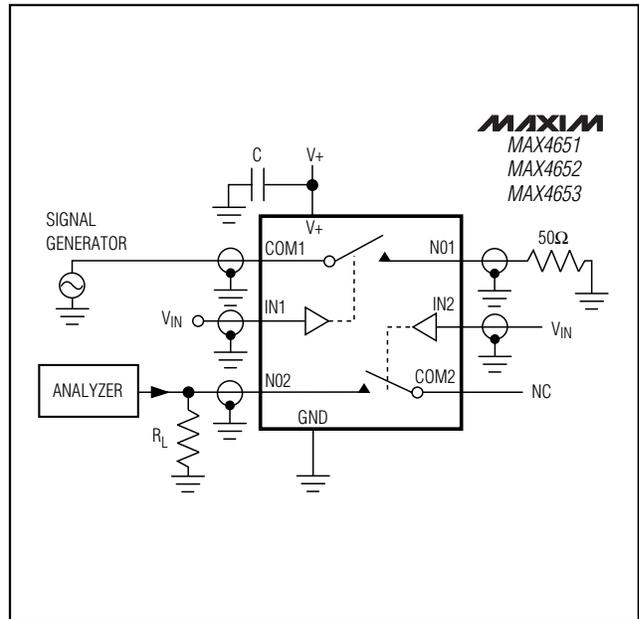


Figure 5. Crosstalk Test Circuit

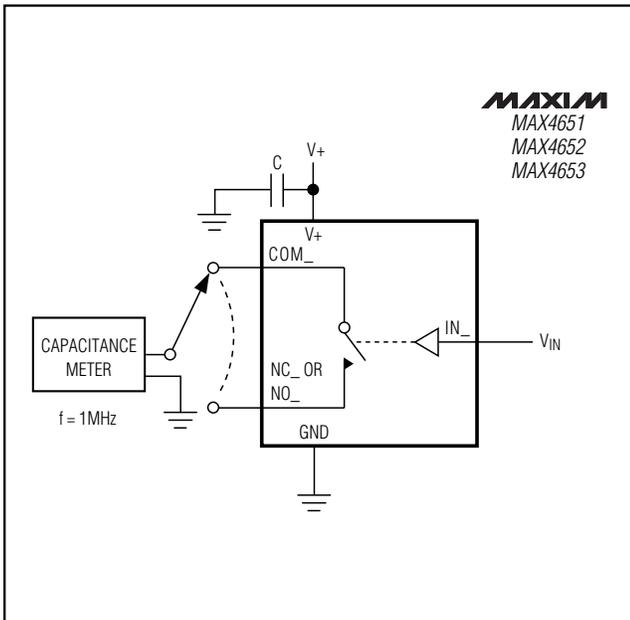


Figure 6. Switch Off-Capacitance Test Circuit

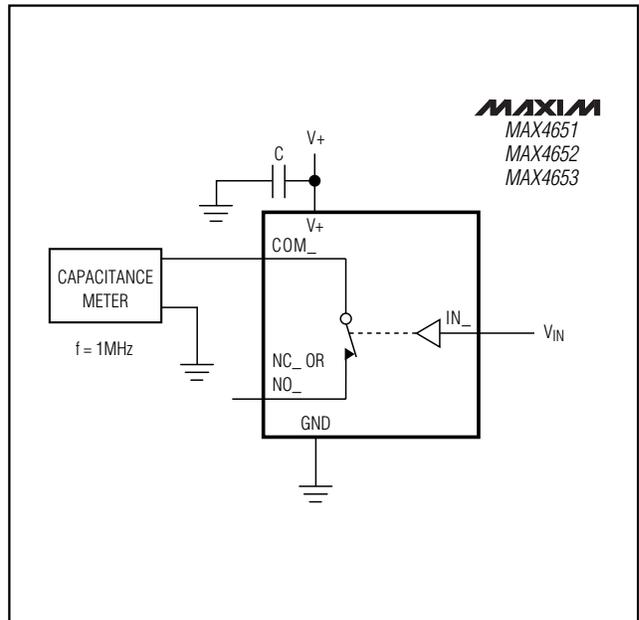


Figure 7. Switch On-Capacitance Test Circuit

# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Package Information

MAX4651/MAX4652/MAX4653

TOP VIEW

BOTTOM VIEW

EXPOSED DIE PAD

SYMBOL	COMMON DIMENSIONS			
	MILLIMETERS		INCHES	
A	MIN.	MAX.	MIN.	MAX.
A <sub>1</sub>	0.05	0.15	.002	.006
A <sub>2</sub>	0.85	0.95	.033	.037
b	0.19	0.30	.007	.012
b <sub>1</sub>	0.19	0.25	.007	.010
c	0.090	0.20	.0035	.008
c <sub>1</sub>	0.090	0.135	.0035	.0053
D	SEE VARIATIONS		SEE VARIATIONS	
E	4.30	4.50	.169	.177
e	0.65 BSC		.026 BSC	
H	6.25	6.50	.246	.256
L	0.50	0.70	.020	.028
N	SEE VARIATIONS		SEE VARIATIONS	
Y	2.85	3.15	.112	.124
α	0°	8°	0°	8°

SIDE VIEW

END VIEW

SEATING PLANE

SEE DETAIL "A"

JEDEC	N	VARIATIONS				
		MILLIMETERS		INCHES		
MD-153		MIN.	MAX.	MIN.	MAX.	
AB	14	D	4.90	5.10	.193	.201
AC	16	D	4.90	5.10	.193	.201
AC-EP	16	D	4.90	5.10	.193	.201
		X	2.85	3.15	.112	.124
AD	20	D	6.40	6.60	.252	.260
AD-EP	20	D	6.40	6.60	.252	.260
		X	4.00	4.34	.157	.171
AE	24	D	7.70	7.90	.303	.311
AF	28	D	9.60	9.80	.378	.386
AF-EP		D	9.60	9.80	.378	.386
		X	5.35	5.65	.211	.222

DETAIL "A"

LEAD TIP DETAIL

NOTES:

- DIMENSIONS D AND E DO NOT INCLUDE FLASH.
- MOLD FLASH OR PROTRUSIONS NOT TO EXCEED .15 mm PER SIDE.
- CONTROLLING DIMENSION: MILLIMETER.
- MEETS JEDEC OUTLINE MD-153 VARIATIONS AB, AC, AD, AE, AF.
- DIMENSIONS X AND Y APPLY TO EXPOSED PAD (EP) VERSIONS ONLY.
- EXPOSED PAD FLUSH WITH BOTTOM OF PACKAGE WITHIN .002°.

PROPRIETARY INFORMATION

TITLE: PACKAGE OUTLINE, TSSOP, 4.40mm BODY, 0.65mm PITCH

APPROVAL	DOCUMENT CONTROL NO.	REV	1/1
	21-0066	C	

TSSOP-EP

**Note:** The MAX4651/MAX4652/MAX4653 do not come in an exposed-pad package.

# Low-Voltage, 4Ω, Quad, SPST, CMOS Analog Switches

## Package Information (continued)

	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A1	0.004	0.010	0.10	0.25
B	0.014	0.019	0.35	0.49
C	0.007	0.010	0.19	0.25
e	0.050		1.27	
E	0.150	0.157	3.80	4.00
H	0.228	0.244	5.80	6.20
h	0.010	0.020	0.25	0.50
L	0.016	0.050	0.40	1.27

	INCHES		MILLIMETERS		N	MS012
	MIN	MAX	MIN	MAX		
D	0.189	0.197	4.80	5.00	8	A
D	0.337	0.344	8.55	8.75	14	B
D	0.386	0.394	9.80	10.00	16	C

NOTES:  
 1. D&E DO NOT INCLUDE MOLD FLASH  
 2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED .15mm (.006")  
 3. LEADS TO BE COPLANAR WITHIN .102mm (.004")  
 4. CONTROLLING DIMENSION: MILLIMETER  
 5. MEETS JEDEC MS012-XX AS SHOWN IN ABOVE TABLE  
 6. N = NUMBER OF PINS

**MAXIM** 120 SAN GABRIEL DR. SUNNYVALE, CA 94086 FAX (408) 737-7700 PROPRIETARY INFORMATION TITLE PACKAGE FAMILY OUTLINE: SOIC .150" 1/1 21-0041 A DOCUMENT CONTROL NUMBER REV

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